FEATURES

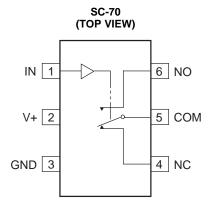
- Isolation in Power-Down Mode, V₊ = 0
- Specified Break-Before-Make Switching
- Low ON-State Resistance (1 Ω)
- Control Inputs Are 5.5-V Tolerant
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 1.65-V to 5.5-V Single-Supply Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

APPLICATIONS

- Cell Phones
- PDAs
- Portable Instrumentation
- Audio and Video Signal Routing
- Low-Voltage Data-Acquisition Systems
- Communication Circuits
- Modems
- Hard Drives
- Computer Peripherals
- Wireless Terminals and Peripherals

DESCRIPTION

The TS5A4624 is a single-pole double-throw (SPDT) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers low ON-state resistance and excellent ON-state resistance matching with the break-before-make feature, to prevent signal distortion during the transferring of a signal from one channel to another. The device has an excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.



Switches are shown for logic 0 input.

FUNCTION TABLE

IN	NC TO COM, COM TO NC	NO TO COM, COM TO NO
L	ON	OFF
Н	OFF	ON



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



SUMMARY OF CHARACTERISTICS(1)

Configuration	2:1 Multiplexer/ Demultiplexer (1 × SPDT)
Number of channels	1
ON-state resistance r _{on})	1.1 Ω
ON-state resistance match (Δr _{on})	0.1 Ω
ON-state resistance flatness r _{on(flat)})	0.15 Ω
Turn-on/turn-off time (t _{ON/tOFF})	20 ns/15 ns
Break-before-make time (t _{BBM})	12 ns
Charge injection (Q _C)	–20 pC
Bandwidth (BW)	100 MHz
OFF isolation (O _{ISO})	-65 dB at 1 MHz
Crosstalk (X _{TALK})	-66 dB at 1 MHz
Total harmonic distortion (THD)	0.01%
Leakage current (I _{NO(OFF)} /I _{NC(OFF)})	±20 nA
Power-supply current (I ₊)	0.1 μΑ
Package options	6-pin DCK

(1) $V_{+} = 5 \text{ V}, T_{A} = 25^{\circ}\text{C}$

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING(2)
–40°C to 85°C	SOT (SC-70) - DCK	Tape and reel	TS5A4624DCKR	JW_

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

⁽²⁾ DCK: The actual top-side marking has one additional character that designates the assembly/test site.

Absolute Minimum and Maximum Ratings (1)(2)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V ₊	Supply voltage range ⁽³⁾		-0.5	6.5	V
V _{NO} V _{NC} V _{COM}	Analog voltage range ⁽³⁾⁽⁴⁾⁽⁵⁾				
I_{K}	Analog port diode current	-50		mA	
I _{NO}	On-state switch current	-200	200		
I _{NC} I _{COM}	On-state peak switch current ⁽⁶⁾	On-state peak switch current ⁽⁶⁾ V _{NO} , V _{NC} , V _{COM} = 0 to V ₊		400	mA
V_{I}	Digital input voltage range (3)(4)		-0.5	6.5	V
I_{IK}	Digital input clamp current	V ₁ < 0	-50		mA
I ₊	Continuous current through V ₊			100	mA
I _{GND}	Continuous current through GND	ontinuous current through GND			
θ_{JA}	Package thermal impedance (7)	age thermal impedance ⁽⁷⁾			
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(3) All voltages are with respect to ground, unless otherwise specified.

(5) This value is limited to 5.5 V maximum.

(6) Pulse at 1-ms duration < 10% duty cycle

(7) The package thermal impedance is calculated in accordance with JESD 51-7.

⁽²⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

⁽⁴⁾ The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

TS5A4624 1- Ω SPDT ANALOG SWITCH 5-V/3.3-V SINGLE-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER



SLYS014A-DECEMBER 2005-REVISED AUGUST 2006

Electrical Characteristics for 5-V Supply⁽¹⁾

 $V_{+} = 4.5 \text{ V}$ to 5.5 V, $T_{A} = -40 ^{\circ}\text{C}$ to 85 $^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	S	T _A	V ₊	MIN	TYP	MAX	UNIT
Analog Switch					I.	l.			
Analog signal range	V_{COM}, V_{NO}, V_{NC}					0		V ₊	V
Peak ON resistance	r _{peak}	$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C Full	4.5 V		0.8	1.1 1.5	Ω
ON-state resistance	r _{on}	V_{NO} or $V_{NC} = 2.5 \text{ V}$, $I_{COM} = -100 \text{ mA}$,	Switch ON, See Figure 13	25°C Full	4.5 V		0.7	0.9 1.1	Ω
ON-state				25°C			0.05	0.1	
resistance match between channels	Δr_{on}	V_{NO} or $V_{NC} = 2.5 \text{ V}$, $I_{COM} = -100 \text{ mA}$,	Switch ON, See Figure 13	Full	4.5 V			0.1	Ω
ON-state		$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C			0.15		
resistance flatness	r _{on(flat)}	V_{NO} or $V_{NC} = 1 \text{ V}$, 1.5 V, 2.5 V,	Switch ON,	25°C	4.5 V		0.1	0.25	Ω
		$I_{COM} = -100 \text{ mA},$	See Figure 13	Full				0.25	
		V_{NC} or $V_{NO} = 1 \text{ V}$, $V_{COM} = 1 \text{ V to } 4.5 \text{ V}$,		25°C		-20	2	20	
NC, NO OFF leakage current	I _{NC(OFF)} , I _{NO(OFF)}	or V _{NC} or V _{NO} = 4.5 V, V _{COM} = 1 V to 4.5 V,	Switch OFF, See Figure 14	Full	5.5 V	-100		100	nA
Carron	I _{NC(PWROFF)} ,	V_{NC} or $V_{NO} = 0$ to 5.5 V,	Switch OFF,	25°C	0 V	-1	0.2	1	μА
	I _{NO(PWROFF)}	$V_{COM} = 5.5 \text{ V to 0},$	See Figure 14	Full	O V	-20		20	μΑ
NC, NO	I _{NC(ON)} ,	V_{NC} or $V_{NO} = 1 V$, $V_{COM} = Open$,	Switch ON,	25°C	551/	-20	2	20	
ON leakage current	I _{NO(ON)}	V_{NC} or $V_{NO} = 4.5 \text{ V}$, $V_{COM} = \text{Open}$,	See Figure 15	Full	5.5 V	-100		100	nA
СОМ		V_{NC} or $V_{NO} = 0$ to 5.5 V,	Switch OFF,	25°		-1	0.1	1	
OFF leakage current	I _{COM(PWROFF)}	$V_{COM} = 5.5 \text{ V to } 0,$	See Figure 14	Full	0 V	-20		20	μΑ
COM		V_{NC} or V_{NO} = Open, V_{COM} = 1 V,	Switch ON,	25°C		-20	2	20	
ON leakage current	I _{COM(ON)}	or V_{NC} or V_{NO} = Open, V_{COM} = 4.5 V,	See Figure 15	Full	5.5 V	-100		100	nA
Digital Input (IN)									
Input logic high	V_{IH}			Full		2.4		5.5	V
Input logic low	V_{IL}			Full		0		0.8	V
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0		25°C Full	5.5 V	-2 100		100	nA

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 5-V Supply⁽¹⁾ (Continued)

 $V_{+} = 4.5 \text{ V to } 5.5 \text{ V}, T_{A} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C} \text{ (unless otherwise noted)}$

PARAMETER	SYMBOL	TEST CON	IDITIONS	TA	V ₊	MIN	TYP	MAX	UNIT
Dynamic	1								
		\/ \/	0 25 -5	25°C	5 V	4	12	22	
Turn-on time	t _{ON}	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C _L = 35 pF, See Figure 17	Full	4.5 V to 5.5 V	2		25	ns
		V - V	$C_1 = 35 pF$,	25°C	5 V	1	5	8	
Turn-off time	t _{OFF}	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	See Figure 17	Full	4.5 V to 5.5 V	1		10	ns
Break-before-		\ \ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\	0 25 -5	25°C	5 V	1	8	13	
make time	t _{BBM}	$\begin{aligned} V_{NC} &= V_{NO} = V_+, \\ R_L &= 50 \ \Omega, \end{aligned}$	$C_L = 35 \text{ pF},$ See Figure 18	Full	4.5 V to 5.5 V	1		15	ns
Charge injection	Q _C	V _{GEN} = 0, R _{GEN} = 0,	C _L = 1 nF, See Figure 22	25°C	5 V		15.5		pC
NC, NO OFF capacitance	C _{NC(OFF)} , C _{NO(OFF)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 16	25°C	5 V		18		pF
NC, NO ON capacitance	$C_{NC(ON)}, \ C_{NO(ON)}$	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 16	25°C	5 V		55		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	5 V		55		pF
Digital input capacitance	Cı	$V_I = V_+ \text{ or GND},$	See Figure 16	25°C	5 V		2		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 19	25°C	5 V		90		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, f = 1 MHz,	Switch OFF, See Figure 20	25°C	5 V		-63		dB
Crosstalk	X _{TALK}	$R_L = 50 \Omega$, f = 1 MHz,	Switch ON, See Figure 21	25°C	5 V		-63		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 200 Hz to 20 kHz, See Figure 23	25°C	5 V		0.004		%
Supply	•	•		•					
Positive supply		$V_1 = V_{\perp}$ or GND,	Switch ON or OFF	25°C	5.5 V		10	50	nA
current	I ₊	$v_{\parallel} = v_{+} \cup i \cup i \cup i$	SWILCH ON UI OFF	Full	0.0 v			500	IIA

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

TS5A4624 1- Ω SPDT ANALOG SWITCH 5-V/3.3-V SINGLE-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER



SLYS014A-DECEMBER 2005-REVISED AUGUST 2006

Electrical Characteristics for 3.3-V Supply⁽¹⁾

 $\rm V_{\scriptscriptstyle +} = 3~V$ to 3.6 V, $\rm T_{\rm A} = -40^{\circ}C$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	}	TA	V ₊	MIN	TYP	MAX	UNIT
Analog Switch						•			
Analog signal range	$V_{\text{COM}}, V_{\text{NO}}, V_{\text{NC}}$					0		V ₊	V
Peak ON resistance	r _{peak}	$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C Full	3 V		1.3	1.6	Ω
ON-state resistance	r _{on}	V_{NO} or $V_{NC} = 2 V$, $I_{COM} = -100 \text{ mA}$,	Switch ON, See Figure 13	25°C Full	3 V		1.2	1.5 1.7	Ω
ON-state resistance match between channels	$\Delta r_{ m on}$	V_{NO} or $V_{NC} = 2 \text{ V}$, 0.8 V, $I_{COM} = -100 \text{ mA}$,	Switch ON, See Figure 13	25°C Full	3 V		0.1	0.15	Ω
ON-state		$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 13	25°C			0.2		
resistance flatness	r _{on(flat)}	V_{NO} or $V_{NC} = 2 \text{ V}$, 0.8 V, $I_{COM} = -100 \text{ mA}$,	Switch ON, See Figure 13	25°C Full	3 V		0.15	0.3	Ω
	I _{NC(OFF)} ,	V_{NC} or $V_{NO} = 1$ V, $V_{COM} = 1$ V to 3 V,	Switch OFF,	25°C		-20	2	20	
NC, NO OFF leakage	I _{NO(OFF)}	or V_{NC} or $V_{NO} = 3 \text{ V}$, $V_{COM} = 1 \text{ V}$ to 3 V,	See Figure 14	Full	3.6 V	-50		50	nA
current	I _{NC(PWROFF)} , I _{NO(PWROFF)}	V_{NC} or $V_{NO} = 0$ to 3.6 V, $V_{COM} = 3.6$ V to 0,	Switch OFF, See Figure 14	25°C Full	0 V	-1 -15	0.2	1 15	μА
NC, NO ON leakage current	I _{NC(ON)} , I _{NO(ON)}	V_{NC} or $V_{NO} = 1$ V, $V_{COM} = Open$, or V_{NC} or $V_{NO} = 3$ V, $V_{COM} = Open$,	Switch ON, See Figure 15	25°C Full	3.6 V	-10 -20	2	10 20	nA
COM OFF leakage current	I _{COM(PWROFF)}	V _{NC} or V _{NO} = 3.6 V to 0, V _{COM} = 0 to 3.6 V,	Switch OFF, See Figure 14	25° Full	0 V	-1 -15	0.2	1 15	μΑ
COM ON leakage current	I _{COM(ON)}	V_{NC} or V_{NO} = Open, V_{COM} = 1 V, or V_{NC} or V_{NO} = Open, V_{COM} = 3 V,	Switch ON, See Figure 15	25°C Full	3.6 V	-10 -20	2	10 20	nA
Digital Input (IN)	I			1	1	1			
Input logic high	V _{IH}	_		Full		2.4		5.5	V
Input logic low	V _{IL}			Full		0		0.8	V
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0		25°C Full	3.6 V	-2 -100		100	nA

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 3.3-V Supply⁽¹⁾ (Continued)

 $V_{+} = 3 \text{ V to } 3.6 \text{ V}, T_{A} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C} \text{ (unless otherwise noted)}$

PARAMETER	SYMBOL	TEST CONI	DITIONS	T _A	V ₊	MIN	TYP	MAX	UNIT
Dynamic									
		V - V	$C_1 = 35 pF$,	25°C	3.3 V	4	16	25	
Turn-on time	t _{ON}	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	See Figure 17	Full	3 V to 3.6 V	2		27	ns
		$V_{COM} = V_+,$	$C_1 = 35 pF$,	25°C	3.3 V	1	5.5	8	
Turn-off time	t _{OFF}	$R_L = 50 \Omega$	See Figure 17	Full	3 V to 3.6 V	1		11	ns
Break-before-		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	C _L = 35 pF,	25°C	3.3 V	2	12	20	
make time	t _{BBM}	$\begin{aligned} &V_{NC} = V_{NO} = V_+, \\ &R_L = 50 \ \Omega, \end{aligned}$	See Figure 18	Full	3 V to 3.6 V	2		25	ns
Charge injection	$Q_{\mathbb{C}}$	$V_{GEN} = 0,$ $R_{GEN} = 0,$	$C_L = 1 \text{ nF},$ See Figure 22	25°C	3.3 V		9		рC
NC, NO OFF capacitance	C _{NC(OFF)} , C _{NO(OFF)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 16	25°C	3.3 V		18		pF
NC, NO ON capacitance	$C_{NC(ON)}, \ C_{NO(ON)}$	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 16	25°C	3.3 V		55		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	3.3 V		55		pF
Digital input capacitance	Cı	$V_I = V_+ \text{ or GND},$	See Figure 16	25°C	3.3 V		2		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 19	25°C	3.3 V		90		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, f = 1 MHz,	Switch OFF, See Figure 20	25°C	3.3 V		-63		dB
Crosstalk	X _{TALK}	$R_L = 50 \Omega$, f = 1 MHz,	Switch ON, See Figure 21	25°C	3.3 V		-63		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 23	25°C	3.3 V		0.01		%
Supply									
Positive supply	1	$V_1 = V_+$ or GND,	Switch ON or OFF	25°C	3.6 V		10	50	nA
current	I ₊	VI - V+ OI GIVD,		Full	3.0 v			100	11/

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

TS5A4624 1- Ω SPDT ANALOG SWITCH 5-V/3.3-V SINGLE-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER



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Electrical Characteristics for 2.5-V Supply⁽¹⁾

 $\rm V_{\scriptscriptstyle +} = 2.3~V$ to 2.7, $\rm T_{\rm A} = -40^{\circ}C$ to $85^{\circ}C$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T _A	V ₊	MIN	TYP	MAX	UNIT
Analog Switch					·				
Analog signal range	V _{COM} , V _{NO} , V _{NC}					0		V ₊	V
Peak ON resistance	r _{peak}	$ \begin{aligned} 0 &\leq (V_{NO} \text{ or } V_{NC}) \leq V_+, \\ I_{COM} &= -8 \text{ mA}, \end{aligned} $	Switch ON, See Figure 13	25°C Full	2.3 V		1.8	2.5	Ω
ON-state resistance	r _{on}	V_{NO} or $V_{NC} = 1.8 \text{ V}$, $I_{COM} = -8 \text{ mA}$,	Switch ON, See Figure 13	25°C Full	2.3 V		1.5	2.4	Ω
ON-state				25°C			0.15	0.2	
resistance match between channels	$\Delta r_{\sf on}$	V_{NO} or $V_{NC} = 1.8 \text{ V}$, $I_{COM} = -8 \text{ mA}$,	Switch ON, See Figure 13	Full	2.3 V			0.2	Ω
ON-state		$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -8 \text{ mA},$	Switch ON, See Figure 13	25°C			0.6		
resistance flatness	r _{on(flat)}	V_{NO} or $V_{NC} = 0.8 \text{ V}$, 1.8 V, $I_{COM} = -8 \text{ mA}$,	Switch ON, See Figure 13	25°C Full	2.3 V		0.6	1	Ω
		V_{NC} or $V_{NO} = 0.5 \text{ V}$,		25°C		-20	2	20	
NC, NO OFF leakage current	I _{NC(OFF)} , I _{NO(OFF)}	$V_{COM} = 0.5 \text{ V to } 2.3 \text{ V,}$ or $V_{NC} \text{ or } V_{NO} = 2.3 \text{ V,}$ $V_{COM} = 0.5 \text{ V to } 2.3 \text{ V,}$	Switch OFF, See Figure 14	Full	2.7 V	-50		50	nA
Current	I _{NC(PWROFF)} , I _{NO(PWROFF)}	V_{NC} or $V_{NO} = 0$ to 3.6 V, $V_{COM} = 3.6$ V to 0,	Switch OFF, See Figure 14	25°C Full	0 V	-1 -10	0.1	10	μА
NC, NO	,	V _{NC} or V _{NO} = 0.5 V, V _{COM} = Open,	Switch ON.	25°C		-10	2	10	
ON leakage current	I _{NC(ON)} , I _{NO(ON)}	or V_{NC} or $V_{NO} = 2.2 \text{ V}$, $V_{COM} = \text{Open}$,	See Figure 15	Full	2.7 V	-20		20	nA
COM		V_{NC} or $V_{NO} = 2.7 \text{ V to } 0$,	Switch OFF,	25°	0.17	-1	0.1	10	
OFF leakage current	I _{COM(PWROFF)}	V _{COM} = 0 to 2.7 V,	See Figure 14	Full	0 V	-10		10	μΑ
COM		V_{NC} or V_{NO} = Open, V_{COM} = 0.5 V,	Switch ON,	25°C		-10	2	10	
ON leakage current	I _{COM(ON)}	or V_{NC} or V_{NO} = Open, V_{COM} = 2.2 V,	See Figure 15	Full	2.7 V	-20		20	nA
Digital Input (IN)									
Input logic high	V _{IH}			Full		1.8		5.5	V
Input logic low	V _{IL}			Full		0		0.6	V
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0		25°C Full	2.7 V	-2 20		20	nA

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 2.5-V Supply⁽¹⁾ (Continued)

 $V_{+} = 2.3 \text{ V to } 2.7, T_{A} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C} \text{ (unless otherwise noted)}$

PARAMETER	SYMBOL	TEST CONI	DITIONS	T _A	V ₊	MIN	TYP	MAX	UNIT
Dynamic									
		\/ \/	C 25 x 5	25°C	2.5 V	10	22	32	
Turn-on time	t _{ON}	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C _L = 35 pF, See Figure 17	Full	2.3 V to 2.7 V	8		35	ns
		$V_{COM} = V_+,$	$C_1 = 35 pF,$	25°C	2.5 V	3	6	11	
Turn-off time	t _{OFF}	$R_L = 50 \Omega$	See Figure 17	Full	2.3 V to 2.7 V	2		12	ns
Break-before-		V - V - V	C _L = 35 pF,	25°C	2.5 V	5	19	30	
make time	t _{BBM}	$\begin{aligned} &V_{NC} = V_{NO} = V_+, \\ &R_L = 50 \ \Omega, \end{aligned}$	See Figure 18	Full	2.3 V to 2.7 V	5		35	ns
Charge injection	Q _C	$V_{GEN} = 0,$ $R_{GEN} = 0,$	$C_L = 1 \text{ nF},$ See Figure 22	25°C	2.5 V		-7		рC
NC, NO OFF capacitance	C _{NC(OFF)} , C _{NO(OFF)}	V _{NC} or V _{NO} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	2.5 V		18		pF
NC, NO ON capacitance	$C_{NC(ON)}, \ C_{NO(ON)}$	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 16	25°C	2.5 V		55		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	2.5 V		55		pF
Digital input capacitance	Cı	$V_I = V_+$ or GND,	See Figure 16	25°C	2.5 V		2		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 19	25°C	2.5 V		90		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, f = 1 MHz,	Switch OFF, See Figure 20	25°C	2.5 V		-63		dB
Crosstalk	X _{TALK}	$R_L = 50 \Omega$, f = 1 MHz,	Switch ON, See Figure 21	25°C	2.5 V		-63		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 23	25°C	2.5 V		0.02		%
Supply	•								
Positive supply	1	$V_1 = V_+$ or GND,	Switch ON or OFF	25°C	2.7 V		10	20	nA
current	I ₊	VI = V+ OI GIND,	SWILCH ON OF OFF	Full	2.1 V			150	IIA

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

TS5A4624 1- Ω SPDT ANALOG SWITCH 5-V/3.3-V SINGLE-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER



SLYS014A-DECEMBER 2005-REVISED AUGUST 2006

Electrical Characteristics for 1.8-V Supply⁽¹⁾

 V_{+} = 1.65 V to 1.95 V, T_{A} = -40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CON	DITIONS	T _A	V ₊	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}, V_{NC}					0		V ₊	V
Peak ON resistance	r _{peak}	$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -2 \text{ mA},$	Switch ON, See Figure 13	25°C Full	1.65 V		5	15	Ω
ON-state resistance	r _{on}	V_{NO} or $V_{NC} = 1.5 \text{ V}$, $I_{COM} = -2 \text{ mA}$,	Switch ON, See Figure 13	25°C Full	1.65 V		2	2.5 3.5	Ω
ON-state				25°C			0.15	0.4	
resistance match between channels	$\Delta r_{\sf on}$	V_{NO} or $V_{NC} = 1.5 \text{ V}$, $I_{COM} = -2 \text{ mA}$,	Switch ON, See Figure 13	Full	1.65 V			0.4	Ω
ON-state		$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -8 \text{ mA},$	Switch ON, See Figure 13	25°C			5		
resistance flatness	r _{on(flat)}	V_{NO} or $V_{NC} = 0.6 \text{ V}$, 1.5 V,	Switch ON,	25°C	1.65 V		4.5		Ω
natiooo		$I_{COM} = -2 \text{ mA},$	See Figure 13	Full					
		V_{NC} or $V_{NO} = 0.3 \text{ V}$,		25°C		-5	2	5	
NC, NO OFF leakage current	I _{NC(OFF)} , I _{NO(OFF)}	$V_{COM} = 0.3 \text{ V to } 1.65 \text{ V,}$ or V_{NC} or $V_{NO} = 1.65 \text{ V,}$ $V_{COM} = 0.3 \text{ V to } 1.65 \text{ V,}$	Switch OFF, See Figure 14	Full	1.95 V	-20		20	nA
ouo	I _{NC(PWROFF)} ,	V_{NC} or $V_{NO} = 0$ to 1.95 V,	Switch OFF,	25°C	0 V	-1	0.1	1	μА
	I _{NO(PWROFF)}	$V_{COM} = 1.95 \text{ V to 0},$	See Figure 14	Full	UV	-5		5	μΑ
NO NO		V_{NC} or $V_{NO} = 0.3 \text{ V}$,		25°C		-5	2	5	
NC, NO ON leakage current	I _{NC(ON)} , I _{NO(ON)}	V_{COM} = Open, or V_{NC} or V_{NO} = 1.65 V, V_{COM} = Open,	Switch ON, See Figure 15	Full	1.95 V	-20		20	nA
COM		V_{NC} or $V_{NO} = 1.95 \text{ V to } 0$,	Switch OFF,	25°		-1	0.1	1	
OFF leakage current	ICOM(PWROFF)	$V_{COM} = 0 \text{ to } 1.95 \text{ V},$	See Figure 14	Full	0 V	-5		5	μΑ
		V _{NC} or V _{NO} = Open,		25°C		-5	2	5	
COM ON leakage current	I _{COM(ON)}	$V_{COM} = 0.3 \text{ V},$ or $V_{NC} \text{ or } V_{NO} = \text{Open},$ $V_{COM} = 1.65 \text{ V},$	Switch ON, See Figure 15	Full	1.95 V	-20		20	nA
Digital Input (IN)				· · · · · · · · · · · · · · · · · · ·					
Input logic high	V _{IH}			Full		1.5		5.5	V
Input logic low	V _{IL}			Full		0	-	0.6	V
Input leakage	I _{IH} , I _{IL}	V _I = 5.5 V or 0		25°C	1.95 V	-2		2	nA
current	'IH', 'IL	V ₁ = 0.0 V 01 0		Full	1.55 V	20		20	11/

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 1.8-V Supply⁽¹⁾ (Continued)

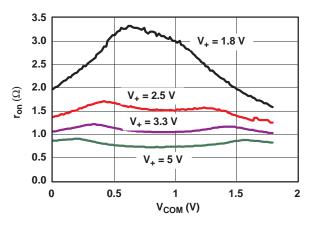
 $V_{+} = 1.65 \text{ V}$ to 1.95 V, $T_{A} = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONI	DITIONS	TA	V ₊	MIN	TYP	MAX	UNIT
Dynamic	1	T.		1					
		W W	0 05 - 5	25°C	1.8 V	17	35	65	
Turn-on time	t _{ON}	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C _L = 35 pF, See Figure 17	Full	1.65 V to 1.95 V	15		70	ns
		V V	0 25 - 5	25°C	1.8 V	3	7	13	
Turn-off time	t _{OFF}	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C _L = 35 pF, See Figure 17	Full	1.65 V to 1.95 V	2		15	ns
Dunal, hafana		V V V	0 25 - 5	25°C	1.8 V	15	33	60	
Break-before- make time	t _{BBM}	$\begin{aligned} V_{NC} &= V_{NO} = V_+, \\ R_L &= 50 \ \Omega, \end{aligned}$	C _L = 35 pF, See Figure 18	Full	1.65 V to 1.95 V	15		65	ns
Charge injection	Q _C	V _{GEN} = 0, R _{GEN} = 0,	C _L = 1 nF, See Figure 22	25°C	1.8 V		4		рС
NC, NO OFF capacitance	C _{NC(OFF)} , C _{NO(OFF)}	V _{NC} or V _{NO} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	1.8 V		18		pF
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 16	25°C	1.8 V		55		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	1.8 V		55		pF
Digital input capacitance	C _I	$V_I = V_+$ or GND,	See Figure 16	25°C	1.8 V		2		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 19	25°C	1.8 V		90		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, f = 1 MHz,	Switch OFF, See Figure 20	25°C	1.8 V		63		dB
Crosstalk	X _{TALK}	$R_L = 50 \Omega$, f = 1 MHz,	Switch ON, See Figure 21	25°C	1.8 V		63		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 \text{ pF},$	f = 20 Hz to 20 kHz, See Figure 23	25°C	1.8 V		0.05		%
Supply	•			•					
Positive supply		V – V or CND	Switch ON or OFF	25°C	1.95 V		5	15	^
current	I ₊	$V_I = V_+ \text{ or GND},$	SWILCH ON OF OFF	Full	1.95 V			50	μΑ

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

TYPICAL PERFORMANCE

1.4



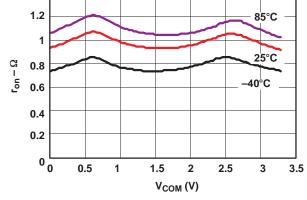
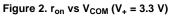
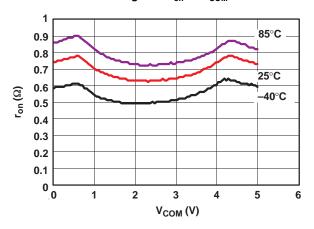


Figure 1. ron vs V_{COM}





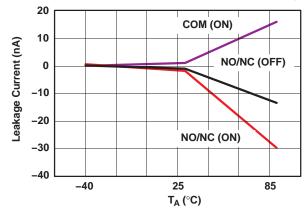
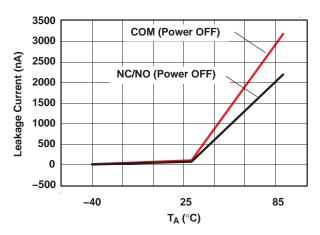


Figure 3. r_{on} vs V_{COM} ($V_{+} = 5$ V)

Figure 4. Leakage Current vs Temperature (V₊ = 3.3 V)



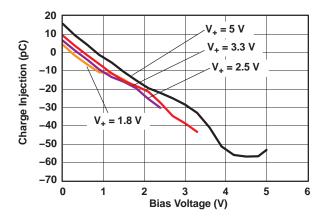


Figure 5. Leakage Current vs Temperature (V₊ = 5 V)

Figure 6. Charge Injection (Q_C) vs V_{COM}

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TYPICAL PERFORMANCE (continued)

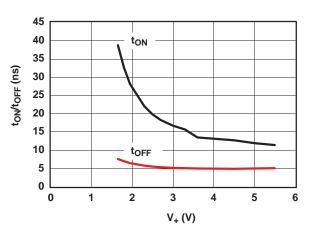


Figure 7. t_{ON} and t_{OFF} vs Supply Voltage

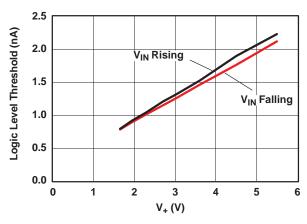


Figure 9. V_{IN} and t_{OFF} vs Supply Voltage

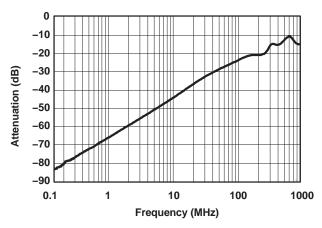


Figure 11. OFF Isolation vs Frequency

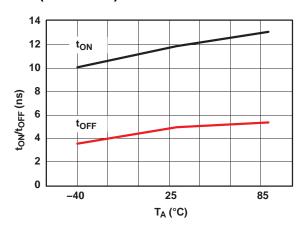


Figure 8. t_{ON} and t_{OFF} vs Temperature

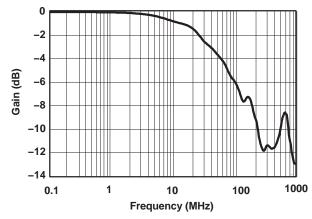


Figure 10. Bandwidth $(V_+ = 5 V)$

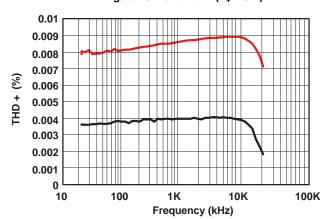


Figure 12. Total Harmonic Distortion vs Frequency $(V_+ = 5 \text{ V})$



TYPICAL PERFORMANCE (continued)

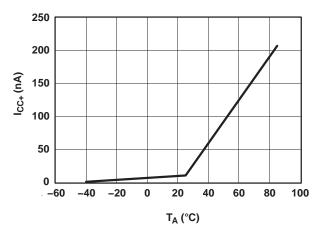


Figure 13. Current vs Temperature $(V_+ = 5 V)$



SLYS014A-DECEMBER 2005-REVISED AUGUST 2006

PIN DESCRIPTION

PIN NO.	NAME	DESCRIPTION				
1	IN	Digital control to connect COM to NO				
2	V ₊	Power supply				
3	GND	Digital ground				
4	NC	Normally closed				
5	COM	Common				
6	NO	Normally open				

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SLYS014A-DECEMBER 2005-REVISED AUGUST 2006

PARAMETER DESCRIPTION

SYMBOL	DESCRIPTION
V _{COM}	Voltage at COM
V _{NC}	Voltage at NC
V _{NO}	Voltage at NO
r _{on}	Resistance between COM and NC or COM and NO ports when the channel is ON
r _{peak}	Peak ON-state resistance over a specified voltage range
Δr_{on}	Difference of r _{on} between channels
r _{on(flat)}	Difference between the maximum and minimum value of ron in a channel over the specified range of conditions
I _{NC(OFF)}	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the OFF state under worst-case input and output conditions
I _{NC(PWROFF)}	Leakage current measured at the NC port during the power-down condition, $V_{+} = 0$
I _{NO(OFF)}	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state under worst-case input and output conditions
I _{NO(PWROFF)}	Leakage current measured at the NO port during the power-down condition, $V_{+} = 0$
I _{NC(ON)}	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the ON state and the output (COM) being open
I _{NO(ON)}	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) being open
I _{COM(ON)}	Leakage current measured at the COM port, with the corresponding channel (COM to NO or COM to NC) in the ON state and the output (NC or NO) being open
I _{COM(PWROFF)}	Leakage current measured at the COM port during the power-down condition, $V_{+} = 0$
V_{IH}	Minimum input voltage for logic high for the control input (IN)
V_{IL}	Maximum input voltage for logic low for the control input (IN)
V_{I}	Voltage at IN
I _{IH} , I _{IL}	Leakage current measured at IN
t _{ON}	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog outputs (COM, NC, or NO) signal when the switch is turning ON.
t _{OFF}	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog outputs (COM, NC, or NO) signal when the switch is turning OFF.
t _{BBM}	Break-before-make time. This parameter is measured under the specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO) when the control signal changes state.
$Q_{\mathbb{C}}$	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NC, NC or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_O$, C_L is the load capacitance and ΔVO is the change in analog output voltage.
C _{NC(OFF)}	Capacitance at the NC port when the corresponding channel (NC to COM) is OFF
C _{NO(OFF)}	Capacitance at the NO port when the corresponding channel (NO to COM) is OFF
C _{NC(ON)}	Capacitance at the NC port when the corresponding channel (NC to COM) is ON
C _{NO(ON)}	Capacitance at the NO port when the corresponding channel (NO to COM) is ON
C _{COM(ON)}	Capacitance at the COM port when the corresponding channel (COM to NC or COM to NO) is ON
C _{IN}	Capacitance of IN
OISO	OFF isolation of the switch is a measurement OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM or NO to COM) in the OFF state.
X _{TALK}	Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC to NO or No). This is measured in a specific frequency and in dB.
BW	Bandwidth of the switch. This is the frequency in which the gain of an ON channel is -3 dB below the DC gain.
THD	Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic.
I ₊	Static power-supply current with the control (IN) pin at V ₊ or GND



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SLYS014A-DECEMBER 2005-REVISED AUGUST 2006

PARAMETER MEASUREMENT INFORMATION

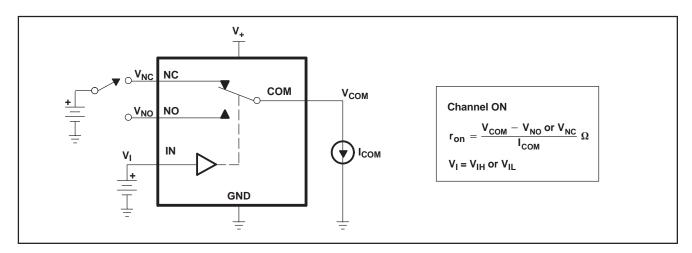
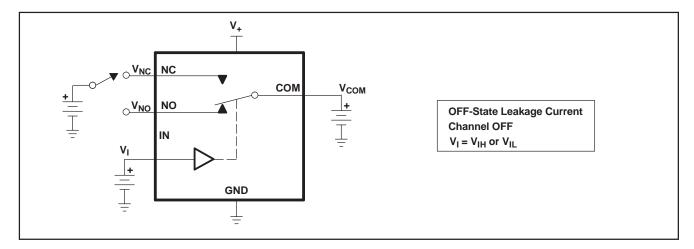


Figure 14. ON-State Resistance (r_{on})



 $\textbf{Figure 15. OFF-State Leakage Current (I_{NC(OFF)}, I_{NC(PWROFF)}, I_{NO(OFF)}, I_{NO(PWROFF)}, I_{COM(OFF)}, I_{COM(PWROFF)})}$

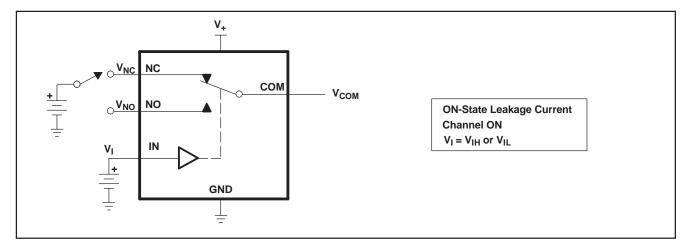
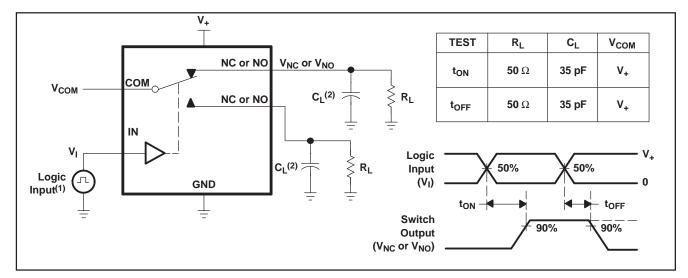


Figure 16. ON-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$, $I_{NO(ON)}$)

٧ NC Capacitance $V_{BIAS} = V_{+} \text{ or GND}$ Meter \circ NO $V_I = V_+ \text{ or GND}$ ○ V_{COM} COM Capacitance is measured at NC, VBIAS IN NO, COM, and IN inputs during \circ^{V_l} ON and OFF conditions. **GND**

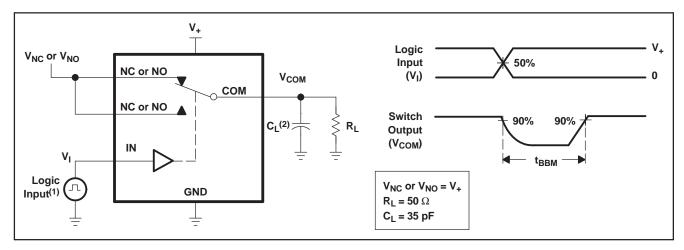
Figure 17. Capacitance (C_I, $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NO(OFF)}$, $C_{NC(ON)}$, $C_{NO(ON)}$)



- (1) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \ \Omega$, $t_r < 5 \ ns$, $t_f < 5 \text{ ns.}$
- (2) C_L includes probe and jig capacitance.

Figure 18. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})





- (1) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.
- (2) C_L includes probe and jig capacitance.

Figure 19. Break-Before-Make Time (t_{BBM})

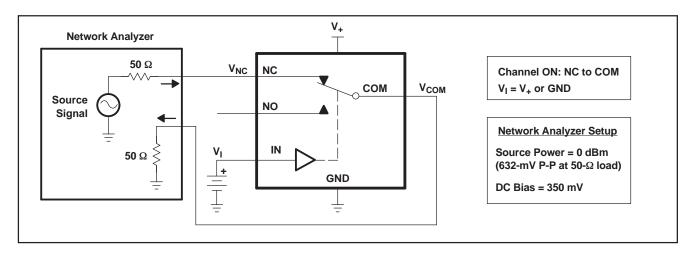


Figure 20. Bandwidth (BW)

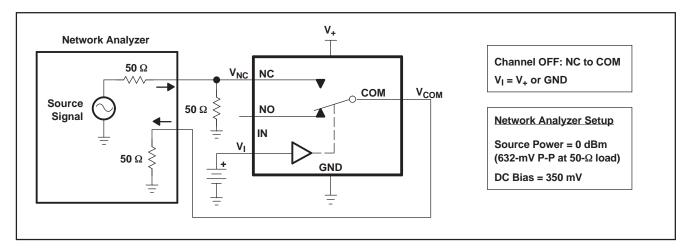
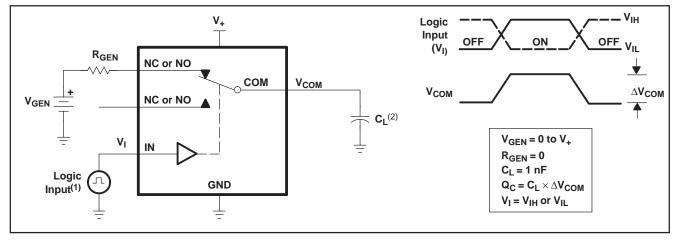


Figure 21. OFF Isolation (OISO)

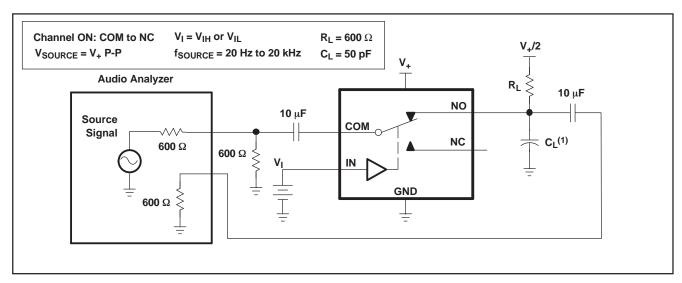
Network Analyzer Channel ON: NC to COM **50** Ω Channel OFF: NO to COM V_{NC} NC V_{COM} $V_I = V_+ \text{ or GND}$ Source V_{NO} NO Signal **Network Analyzer Setup 50** Ω \geqslant IN 50 Ω Source Power = 0 dBm (632-mV P-P at 50- Ω load) **GND** DC Bias = 350 mV

Figure 22. Crosstalk (X_{TALK})



- (1) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω , t_{r} < 5 ns,
- (2) C_L includes probe and jig capacitance.

Figure 23. Charge Injection (Q_C)



(1) C_L includes probe and jig capacitance.

Figure 24. Total Harmonic Distortion (THD)

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)				(6)
						(4)	(5)		
TS5A4624DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(JWF, JWR)
TS5A4624DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(JWF, JWR)
TS5A4624DCKRG4	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	JWF
TS5A4624DCKRG4.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	JWF
TS5A4624DCKT	Obsolete	Production	SC70 (DCK) 6	-	-	Call TI	Call TI	-40 to 85	JWR

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A4624DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
TS5A4624DCKRG4	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3

www.ti.com 18-Jun-2025



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A4624DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
TS5A4624DCKRG4	SC70	DCK	6	3000	180.0	180.0	18.0



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

 4. Falls within JEDEC MO-203 variation AB.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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